Features

- Very High Transmitting Frequency Accuracy Compared to SAW Solutions (Enables Receivers at Lower Bandwidth than With SAW Resonators)
- Lower Cost than the Usual Discrete Solutions Using SAW and Transistors
- Supply Voltage 2.2V to 4.0V in the Temperature Range of -40°C to 85°C
- XTO Output for Clocking the Microcontroller, Thereby, Together with the ATAR090 or ATAR890, Resulting in the Optimum System Cost-effectiveness
- One-chip Solution With Minimum External Circuitry
- Single-ended Open-collector Output (Same Antennas Can Be Used as in Discrete Solutions, Simpler Matching of Magnetic Loop Antennas)
- ESD Protection According to MIL-STD 883 (4 KV HBM) Except Pins XTO1, XTO2, ANT and LF
- Very Small SSO16 Package, Pitch 0.635, 150 mil

1. Description

The ATA2745 is a PLL transmitter IC which has been developed especially for the demands of RF low-cost data transmission systems at data rates up to 20 kBaud.

The transmitting frequency range is 310 MHz to 440 MHz. It can be used in ASK systems. The main applications of the ATA2745 are in the areas of outside temperature metering, socket control, garage door openers, consumption metering, light/fan or airconditioning controls, jalousies, wireless keyboards, and various other consumer market applications.



UHF ASK Transmitter

ATA2745





Figure 1-1. System Block Diagram

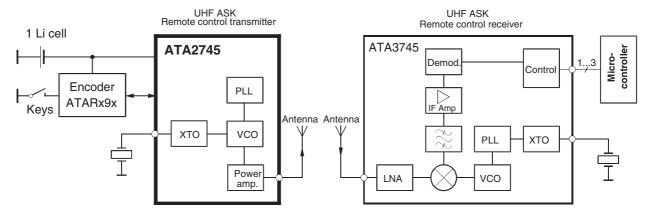
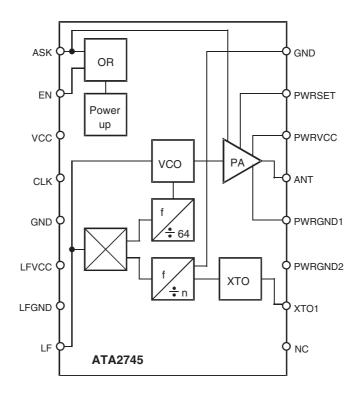


Figure 1-2. Block Diagram



2. Pin Configuration

Figure 2-1. Pinning SSO16

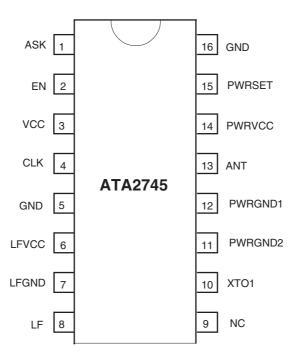


Table 2-1.Pin Description

Pin	Symbol	Function
1	ASK	Modulation input ASK
2	EN	Enable input
3	VCC	Supply voltage
4	CLK	Clock output
5	GND	Ground
6	LFVCC	Supply voltage VCO
7	LFGND	VCO ground
8	LF	Circuit PLL loop
9	NC	Not connected
10	XTO1	Connection for crystal
11	PWRGND2	Power GND2
12	PWRGND1	Power GND1
13	ANT	RF output
14	PWRVCC	Supply voltage power amplifier
15	PWRSET	Applied to VCC
16	GND	Ground



3. General Description

The fully integrated VCO and the single-ended open-collector output allow particularly simple, low-cost RF miniature transmitters to be assembled. The single-ended output enables a considerably simplified adaptation of both a magnetic loop antenna of any form or a λ / 4 antenna. This is because the load impedance must not be balanced as would be the case with a differential output.

The XTO's frequency can be selected to be either 13.56 MHz or 9.844 MHz (USA). At these frequencies, crystals have a very fast start-up time (< 1.5 ms), whereby a wait time of 5 ms to 10 ms is required until the transmitter IC is locked. This means that the processor does not need to poll a lock detect output.

4. Functional Description

4.1 ASK Transmission

The ATA2745 is activated by EN = V_S . V_{ASK} must remain 0V for 5 ms, then the output power can be modulated by means of pin ASK. V_{EN} remains equal to V_S during the transmission of the message. The ASK input activates the power amplifier and the PLL.

4.2 Take-over of the Clock Pulse in the Microcontroller

The clock of the crystal oscillator can be used for clocking the microcontroller. The ATAR090 and ATAR890 have the special feature of starting with an integrated RC oscillator to switch on the ATA2745 with $V_{\rm EN} = V_{\rm S}$. 5 ms later, the 3.39-MHz clock frequency is present, so that the message can be sent with crystal accuracy.

5. Application Circuit

The following component values are recommendations for a typical application. C_4 , C_5 , and C_6 are block capacitors. The values of these capacitors depend on the board layout. $C_4 = 1$ nF, $C_5 = 1$ nF, and $C_6 = 22$ nF are typically used here. For C_5 , the impedance between f = 100 MHz and f = 1 GHz should be as low as possible.

 C_{Loop1} and C_{Loop2} are selected so that the antenna oscillates in resonance and the matching to the appropriate impedance transformation is possible.

 L_{Feed} is an inductor for the antenna's DC current supply. A typical value is L_{Feed} = 220 nH. L_{Feed} can be either printed on the PC board or be a discrete component.

5.1 Output Power Measurement

The following output network (Figure 5-1 on page 5) can be used for output power evaluation, the exact values of L_{10} and C_{10} are dependent on the layout.

 L_{10} and C_{10} form the transformation network to adopt the output impedance of the IC to 50Ω The following table shows the values for an output power of 2 mW and an $R_{PWRSET}=1.2~k\Omega$

Table 5-1. Transformation Network

f [MHz]	C10 [pF]	L10 [nH]	$\mathbf{Z}_{Load\text{-}opt}\left[\Omega\right]$
315	2.7	56	260 + j330
433.92	1.8	33	185 + j268

Figure 5-1. Measurement Output Network

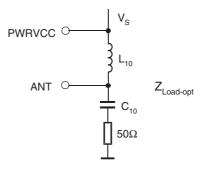
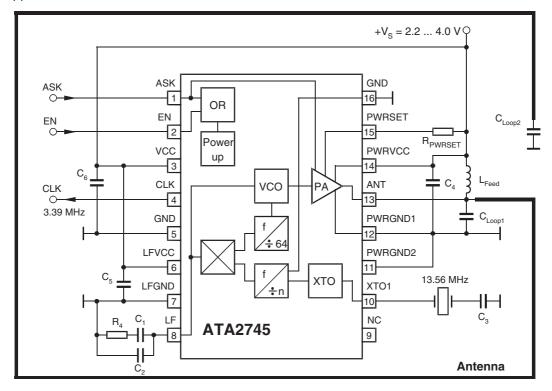


Figure 5-2. Application Circuit





6. Absolute Maximum Ratings

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Parameters	Symbol	Min.	Max.	Unit
Supply voltage	V _S		6	V
Power dissipation	P _{tot}		250	mW
Junction temperature	T _j		150	°C
Storage temperature	T _{stg}	– 55	125	°C
Ambient temperature	T _{amb}	-40	85	°C

Electrostatic sensitive device.

Observe precautions for handling.



7. Thermal Resistance

Parameters	Symbol	Value	Unit
Junction ambient	R_{thJA}	180	K/W

8. Electrical Characteristics

All parameters are referred to GND (pin 5), $V_S = 3V$, $T_{amb} = 25^{\circ}C$, unless otherwise specified The possible operating ranges refer to different circuit conditions: $V_S = 2.2V$ to 4.0V at $T_{amb} = -40^{\circ}C$ to +85°C

Parameters	Test Conditions	Symbol	Min.	Тур.	Max.	Unit
Supply current (power down)	$V_{ASK}, V_{FSK} \le 0.3V, V_{S} < 3.6V$	IS _{off}		2	10	μA
Supply current (power up, output OFF)	$V_{ASK} = GND, V_{EN} = V_S, V_S = 3V$	IS _{on}		4.7	6.2	mA
Supply current (power up, output ON)	$V_{ASK} = V_S$, $V_S = 3V$, $R_{PWRSET} = 1.2 \text{ k}\Omega$	IS _{transmit}		10	12.5	mA
Output power	V_S = 3V, T_{amb} = 25° C, f = 433.92 MHz R_{PWRSET} = 1.2 k Ω	P _{Ref}	1	3	5	dBm
Output power variation for f = 315 MHz compared to f = 433.92 MHz	$f = 315 \text{ MHz}$ $P_{\text{out}} = P_{\text{Ref}} + \Delta P_{\text{Ref}}$	ΔP_{Ref}		1.5		dB
Maximum peak output antenna voltage	At P_{out} = 2.0 mW, the load impedance must be selected to meet the V_{out} maximum requirement, the supply current is not dependent on the load impedance tolerance	$V_{ ext{outmax}}$		V _S – 0.7V		$V_{(peak)}$
Spurious emission	$f_o \pm (n \times f_{PC})$ where $f_{PC} = 6.78$ MHz Load capacitance at CLK ≤ 3 pF f = 230 MHz to 470 MHz f < 230 MHz, $f > 470$ MHz	Em Em			-40 -58	dBC dBC
Oscillator frequency XTO	Crystal frequency = 13.56 MHz	f _{XTO}	13.56 – 30 ppm	13.56	13.56 + 30 ppm	MHz

8. Electrical Characteristics (Continued)

All parameters are referred to GND (pin 5), $V_S = 3V$, $T_{amb} = 25^{\circ}C$, unless otherwise specified The possible operating ranges refer to different circuit conditions: $V_S = 2.2V$ to 4.0V at $T_{amb} = -40^{\circ}C$ to +85°C

Parameters	Test Conditions	Symbol	Min.	Тур.	Max.	Unit
Loop bandwidth	For best LO noise Loop filter components: $C_2 = 3.9 \text{ nF}, C_1 = 15 \text{ nF}, R_4 = 220\Omega$	B _{Loop}		100		kHz
Phase noise PLL	Referring to the phase comparator $f_{PC} = 6.78 \text{ MHz}$	PN _{PLL}		-111	-105	dBC/Hz
Phase noise VCO	At 1 MHz At 36 MHz	PN _{VCO} PN _{VCO}		-90 -122		dBC/Hz
Frequency range of the VCO		f _{VCO}	310		440	MHz
Clock output (CMOS microcontroller compatible)		Clk _{out}		f _{out} / 128		MHz
Load capacitance at CLK		C _{CLK}			10	pF
Series resonance R of the crystal	f _{XTO} = 13.56 MHz f _{XTO} = 9.84 MHz	Rs Rs			80 100	Ω
ASK modulation frequency rate	Duty cycle of the modulation signal = 50%	f _{modASK}	0		20	kHz
CLK output - Output current Low - Output current Low - Output current High - Output current High	$\begin{aligned} &V_{CLK} = 0.2 \times V_{S} \\ &V_{CLK} = 0.3 \times V_{S} \\ &V_{CLK} = 0.8 \times V_{S} \\ &V_{CLK} = 0.7 \times V_{S} \end{aligned}$	I _{ol} I _{ol} I _{oh}	150 200 -150 -200		100	μΑ μΑ μΑ μΑ
ASK input - Low level input voltage - High level input voltage - Input current High		V _{ASKI} V _{ASKh} I _{ASKh}	1.7		0.3 140	V V µA
Enable ASK - Low level input voltage - High level input voltage - Input current High		V _{EN} V _{FSKI} V _{FSKh} I _{FSKh}	1.7		0.3 140	V V µA

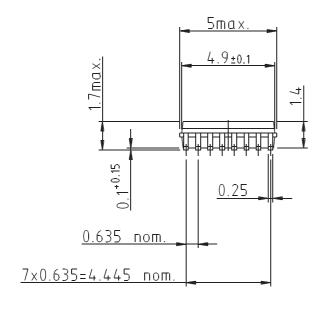


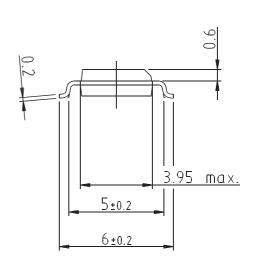


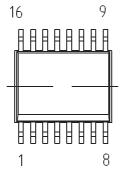
9. Ordering Information

Extended Type Number	Package	Remarks		
ATA2745M-TCQY	SSO16	Taped and reeled, Pb-free		

10. Package Information









Drawing refers to following types: SSO16

Package acc. JEDEC MO 137 AB

11. Revision History

Please note that the following page numbers referred to in this section refer to the specific revision mentioned, not to this document.

Revision No.	History		
4898B-RKE-08/06	Put datasheet in a new template		
4090D-NNE-U0/U0	Section 9 "Ordering Information" on page 8 changed		





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